# **ONSEMÍ**...

# **Bipolar Transistor**

60 V, 3 A, Low  $V_{CE(sat)}$ , NPN Single TP/TP-FA

# 2SC6097

#### Features

- Adoption of FBET, MBIT Process
- Low Collector-to-Emitter Saturation Voltage
- High Allowable Power Dissipation
- Large Current Capacity
- High-Speed Switching

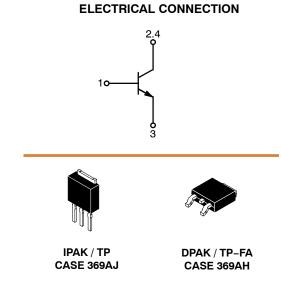
# Applications

• DC / DC Converter, Relay Drivers, Lamp Drivers, Motor Drivers, Inverter

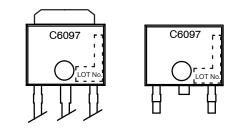
#### SPECIFICATIONS ABSOLUTE MAXIMUM RATINGS at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector to Base Voltage	V <sub>CBO</sub>	-	100	V
Collector to Emitter Voltage	V <sub>CES</sub>	-	100	V
Collector to Emitter Voltage	V <sub>CEO</sub>	-	60	V
Emitter to Base Voltage	V <sub>EBO</sub>	-	6.5	V
Collector Current	Ι <sub>C</sub>	-	3	А
Collector Current (Pulse)	I <sub>CP</sub>	-	5	А
Collector Current	Ι <sub>Β</sub>	-	600	mA
Collector Dissipation	P <sub>C</sub>	-	0.8	W
		$T_{C} = 25^{\circ}C$	15	W
Junction Temperature	Тj	-	150	°C
Storage Temperature	T <sub>stg</sub>	-	– 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



# MARKING DIAGRAM



# **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
2SC6097-E	SC-64, TO-251	500 / Bulk Bag
2SC6097-TL-E	SC-63, TO-252	700 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

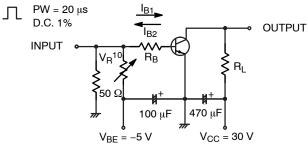
# 2SC6097

# **ELECTRICAL CHARACTERISTICS** (at Ta = $25^{\circ}$ C)

				Ratings		
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0 A	-	-	1	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	$V_{EB} = 4 \text{ V}, \text{ I}_{C} = 0 \text{ A}$	-	-	1	μA
DC Current Gain	h <sub>FE</sub>	$V_{CE} = 2 \text{ V}, \text{ I}_{C} = 100 \text{ mA}$	300	-	600	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 500 mA	-	390	-	MHz
Output Capacitance	Cob	V <sub>CB</sub> = 10 V, f = 1MHz	-	18	-	pF
Collector to Emitter Saturation Voltage	V <sub>CE</sub> (sat)1	I <sub>C</sub> = 1 A, I <sub>B</sub> = 50 mA	-	100	150	mV
	V <sub>CE</sub> (sat)2	I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA	-	90	135	mV
Base to Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = 1 A, I <sub>B</sub> = 100 mA	-	0.84	1.2	V
Collector to Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0 A	100	-	-	V
Collector to Emitter Breakdown Voltage	V <sub>(BR)CES</sub>	$I_C$ = 100 $\mu$ A, R <sub>BE</sub> = 0 $\Omega$	100	-	-	V
Collector to Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	$I_C = 1 \text{ mA}, R_{BE} = \infty$	60	-	-	V
Emittert o Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 10 μA, I <sub>C</sub> = 0 A	6.5	-	-	V
Turn-On Time	t <sub>on</sub>	See specified Test Circuit	-	35	-	ns
Storage Time	t <sub>stg</sub>	1	-	680	-	ns
Fall Time	t <sub>f</sub>	1	-	24	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

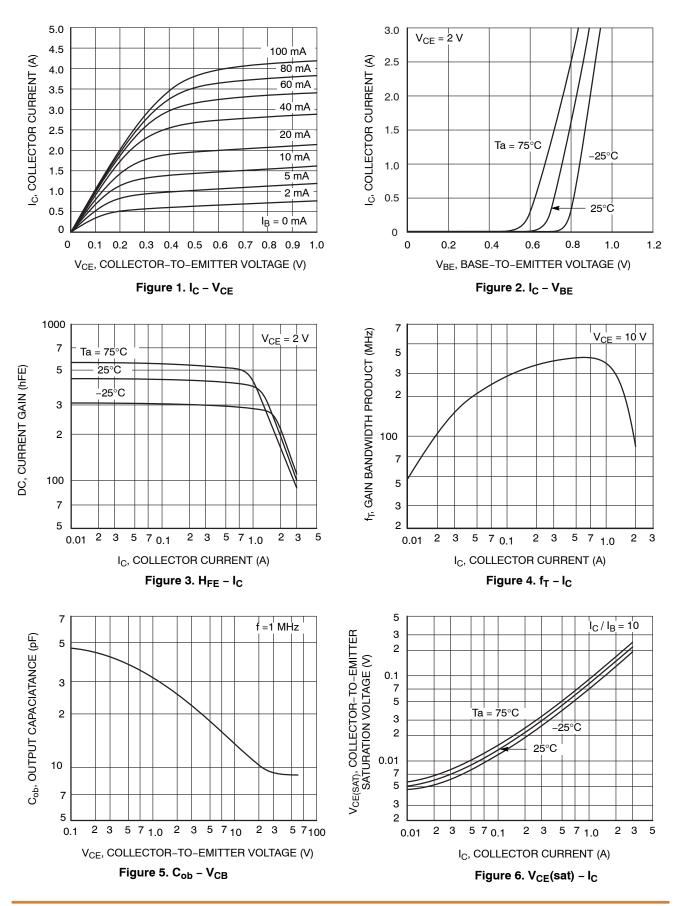
#### Switching Time Test Circuit



I<sub>C</sub> = 10 I<sub>B1</sub>= -10 I<sub>B2</sub> = 0.5 A

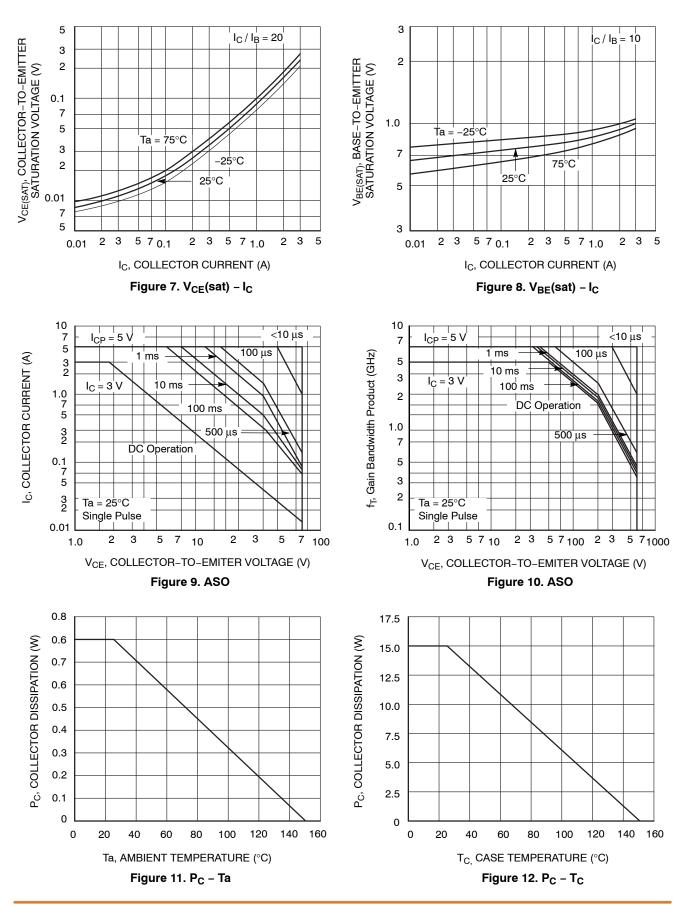
# 2SC6097

#### **TYPICAL CHARACTERISTICS**



## 2SC6097

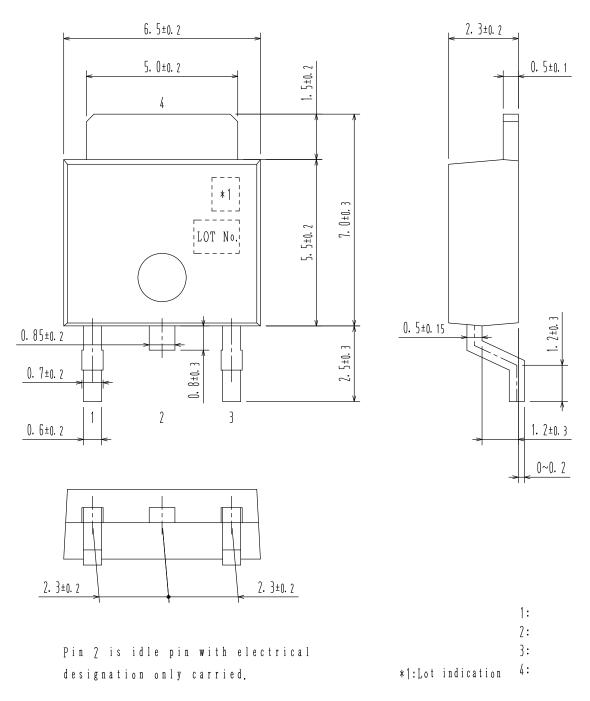
#### TYPICAL CHARACTERISTICS (continued)





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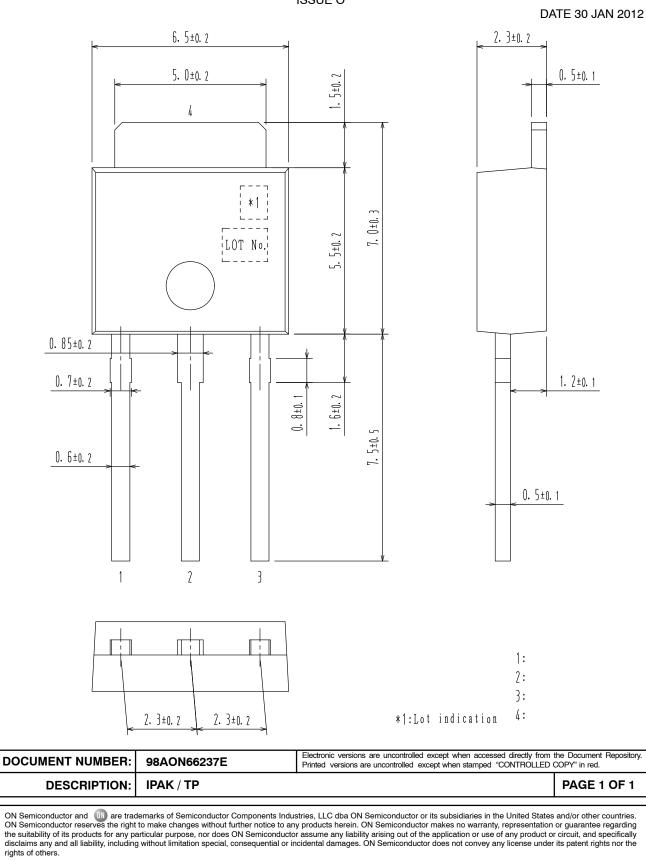
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